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Jameco Part Number 34999

XR-2211

FSK Demodulator/
Tone Decoder

...the analog plus company™

June 1997-3

FEATURES

- Wide Frequency Range, 0.01Hz to 300kHz
- Wide Supply Voltage Range, 4.5V to 20V
- HCMOS/TTL/Logic Compatibility
- FSK Demodulation, with Carrier Detection
- Wide Dynamic Range, 10mV to 3V rms
- Adjustable Tracking Range, ±1% to 80%
- Excellent Temp. Stability, ±50ppm/°C, max.

APPLICATIONS

- Caller Identification Delivery
- FSK Demodulation
- Data Synchronization
- Tone Decoding
- FM Detection
- Carrier Detection

GENERAL DESCRIPTION

The XR-2211 is a monolithic phase-locked loop (PLL) system especially designed for data communications applications. It is particularly suited for FSK modem applications. It operates over a wide supply voltage range of 4.5 to 20V and a wide frequency range of 0.01Hz to 300kHz. It can accommodate analog signals between 10mV and 3V, and can interface with conventional DTL, TTL, and ECL logic families. The circuit consists of a basic PLL for tracking an input signal within the pass band, a quadrature phase detector which provides carrier detection, and an FSK voltage comparator which provides FSK demodulation. External components are used to independently set center frequency, bandwidth, and output delay. An internal voltage reference proportional to the power supply is provided at an output pin.

The XR-2211 is available in 14 pin packages specified for military and industrial temperature ranges.

ORDERING INFORMATION

Part No.	Package	Operating Temperature Range
XR-2211M	14 Pin CDIP (0.300”)	-55°C to +125°C
XR-2211N	14 Pin CDIP (0.300”)	-40°C to +85°C
XR-2211P	14 Pin PDIP (0.300”)	-40°C to +85°C
XR-2211ID	14 Lead SOIC (Jedec, 0.150”)	-40°C to +85°C

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BLOCK DIAGRAM

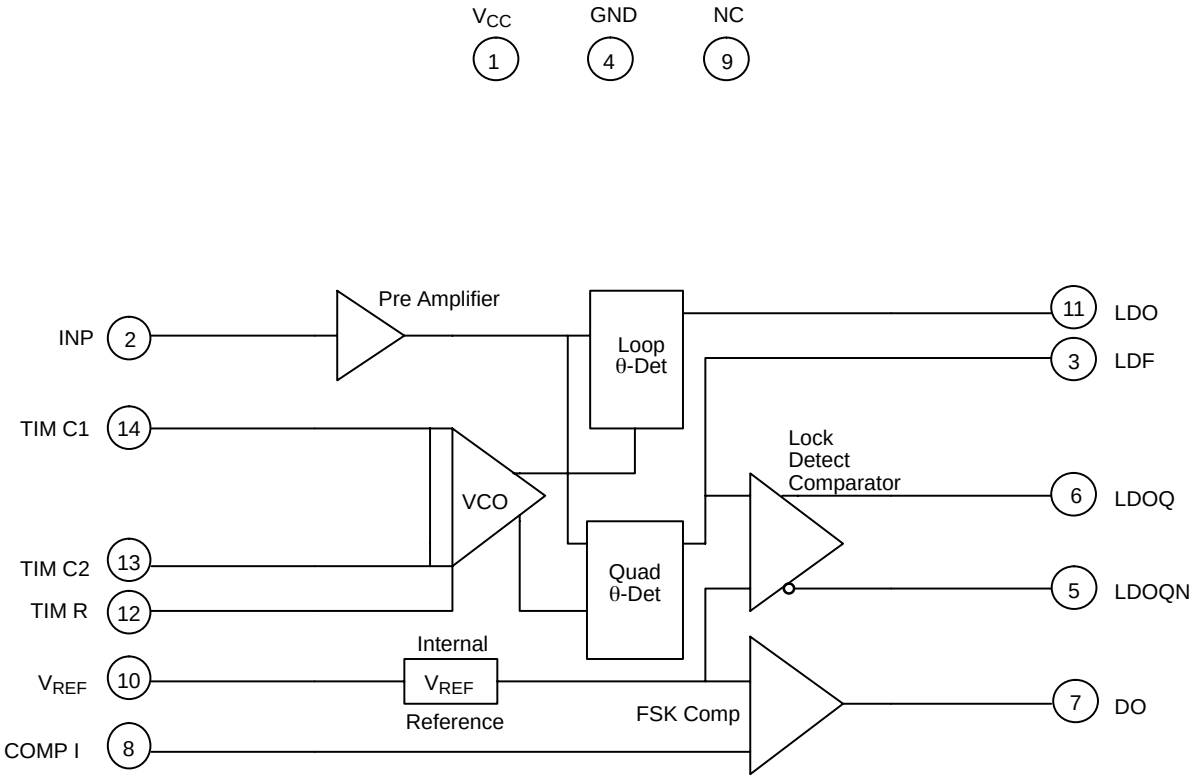
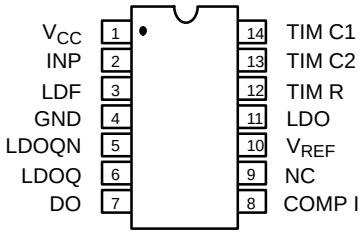
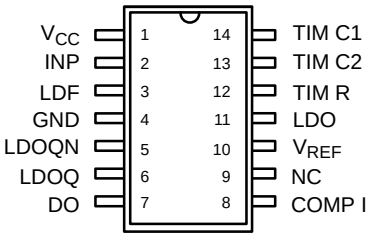


Figure 1. XR-2211 Block Diagram

PIN CONFIGURATION



14 Lead CDIP, PDIP (0.300")



14 Lead SOIC (Jedec, 0.150")

PIN DESCRIPTION

Pin #	Symbol	Type	Description
1	V_{CC}		**Positive Power Supply.**
2	INP	I	**Receive Analog Input.**
3	LDF	O	**Lock Detect Filter.**
4	GND		**Ground Pin.**
5	LDOQN	O	**Lock Detect Output Not.** This output will be low if the VCO is in the capture range.
6	LDOQ	O	**Lock Detect Output.** This output will be high if the VCO is in the capture range.
7	DO	O	**Data Output.** Decoded FSK output.
8	COMP I	I	**FSK Comparator Input.**
9	NC		**Not Connected.**
10	V_{REF}	O	**Internal Voltage Reference.** The value of V_{REF} is V_{CC}/2 - 650mV.
11	LDO	O	**Loop Detect Output.** This output provides the result of the quadrature phase detection.
12	TIM R	I	**Timing Resistor Input.** This pin connects to the timing resistor of the VCO.
13	TIM C2	I	**Timing Capacitor Input.** The timing capacitor connects between this pin and pin 14.
14	TIM C1	I	**Timing Capacitor Input.** The timing capacitor connects between this pin and pin 13.

ELECTRICAL CHARACTERISTICS

Test Conditions: V_{CC} = 12V, T_A = +25°C, R_O = 30KΩ, C_O = 0.033μF, unless otherwise specified.

Parameter	Min.	Typ.	Max.	Unit	Conditions
General					
Supply Voltage	**4.5**		**20**	V	
Supply Current		4	**7**	mA	$R_0 \geq$ 10KΩ. See *Figure 4.*
Oscillator Section					
Frequency Accuracy		±1	**±3**	%	Deviation from $f_O = 1/R_0 C_0$
Frequency Stability					
Temperature		±20	±50	ppm/°C	See *Figure 8.*
Power Supply		0.05	**0.5**	%/V	V_{CC} = 12 ±1V. See *Figure 7.*
		0.2		%/V	V_{CC} = ± 5V. See *Figure 7.*
Upper Frequency Limit	**100**	300		kHz	R_0 = 8.2KΩ, C_0 = 400pF
Lowest Practical Operating Frequency			0.01	Hz	R_0 = 2MΩ, C_0 = 50μF
Timing Resistor, R_0 - See *Figure 5*					
Operating Range	**5**		2000	KΩ	
Recommended Range	5			KΩ	See *Figure 7* and *Figure 8.*
Loop Phase Dectector Section					
Peak Output Current	**±150**	±200	**±300**	μA	Measured at Pin 11
Output Offset Current		1		μA	
Output Impedance		1		MΩ	
Maximum Swing	**±4**	± 5		V	Referenced to Pin 10
Quadrature Phase Detector					Measured at Pin 3
Peak Output Current	**100**	300		μA	
Output Impedance		1		MΩ	
Maximum Swing		11		V_{PP}	
Input Preampt Section					Measured at Pin 2
Input Impedance		20		KΩ	
Input Signal					
Voltage Required to Cause Limiting		2	10	mV rms	

Notes

Parameters are guaranteed over the recommended operating conditions, but are not 100% tested in production.

***Bold face parameters** are covered by production test and guaranteed over operating temperature range.*

DC ELECTRICAL CHARACTERISTICS (CONT'D)

Test Conditions: V_{CC} = 12V, T_A = +25°C, R_O = 30KΩ, C_O = 0.033μF, unless otherwise specified.

Parameter	Min.	Typ.	Max.	Unit	Conditions
Voltage Comparator Section					
Input Impedance		2		MΩ	Measured at Pins 3 and 8
Input Bias Current		100		nA	
Voltage Gain	55	70		dB	R_L = 5.1KΩ
Output Voltage Low		300	**500**	mV	I_C = 3mA
Output Leakage Current		0.01	**10**	μA	V_O = 20V
Internal Reference					
Voltage Level	**4.9**	5.3	**5.7**	V	Measured at Pin 10
Output Impedance		100		Ω	AC Small Signal
Maximum Source Current		80		μA	

Notes
Parameters are guaranteed over the recommended operating conditions, but are not 100% tested in production.
***Bold face parameters** are covered by production test and guaranteed over operating temperature range.*

Specifications are subject to change without notice

ABSOLUTE MAXIMUM RATINGS

Power Supply 20V
Input Signal Level ..... 3V rms
Power Dissipation 900mW

Package Power Dissipation Ratings
CDIP 750mW
  Derate Above T_A = 25°C ..... 8mW/°C
PDIP 800mW
  Derate Above T_A = 25°C ..... 60mW/°C
SOIC 390mW
  Derate Above T_A = 25°C ..... 5mW/°C

SYSTEM DESCRIPTION

The main PLL within the XR-2211 is constructed from an input preamplifier, analog multiplier used as a phase detector and a precision voltage controlled oscillator (VCO). The preamplifier is used as a limiter such that input signals above typically 10mV rms are amplified to a constant high level signal. The multiplying-type phase detector acts as a digital exclusive or gate. Its output (unfiltered) produces sum and difference frequencies of the input and the VCO output. The VCO is actually a current controlled oscillator with its normal input current (f_O) set by a resistor (R_0) to ground and its driving current with a resistor (R_1) from the phase detector.

The output of the phase detector produces sum and difference of the input and the VCO frequencies (internally connected). When in lock, these frequencies are f_{IN}+ f_{VCO} (2 times f_{IN} when in lock) and f_{IN} - f_{VCO} (0Hz when lock). By adding a capacitor to the phase detector output, the 2 times f_{IN} component is reduced, leaving a DC voltage that represents the phase difference between the two frequencies. This closes the loop and allows the VCO to track the input frequency.

The FSK comparator is used to determine if the VCO is driven above or below the center frequency (FSK comparator). This will produce both active high and active low outputs to indicate when the main PLL is in lock (quadrature phase detector and lock detector comparator).

PRINCIPLES OF OPERATION

Signal Input (Pin 2): Signal is AC coupled to this terminal. The internal impedance at pin 2 is 20KΩ. Recommended input signal level is in the range of 10mV rms to 3V rms.

Quadrature Phase Detector Output (Pin 3): This is the high impedance output of quadrature phase detector and is internally connected to the input of lock detect voltage comparator. In tone detection applications, pin 3 is connected to ground through a parallel combination of R_D and C_D (see *Figure 3*) to eliminate the chatter at lock detect outputs. If the tone detect section is not used, pin 3 can be left open.

Lock Detect Output, Q (Pin 6): The output at pin 6 is at "low" state when the PLL is out of lock and goes to "high" state when the PLL is locked. It is an open collector type output and requires a pull-up resistor, R_L, to V_{CC} for proper operation. At "low" state, it can sink up to 5mA of load current.

Lock Detect Complement, (Pin 5): The output at pin 5 is the logic complement of the lock detect output at pin 6. This output is also an open collector type stage which can sink 5mA of load current at low or "on" state.

FSK Data Output (Pin 7): This output is an open collector logic stage which requires a pull-up resistor, R_L, to V_{CC} for proper operation. It can sink 5mA of load current. When decoding FSK signals, FSK data output is at "high" or "off" state for low input frequency, and at "low" or "on" state for high input frequency. If no input signal is present, the logic state at pin 7 is indeterminate.

FSK Comparator Input (Pin 8): This is the high impedance input to the FSK voltage comparator. Normally, an FSK post-detection or data filter is connected between this terminal and the PLL phase detector output (pin 11). This data filter is formed by R_F and C_F (see *Figure 3.*) The threshold voltage of the comparator is set by the internal reference voltage, V_{REF}, available at pin 10.

Reference Voltage, V_{REF} (Pin 10): This pin is internally biased at the reference voltage level, V_{REF}: $V_{REF} = V_{CC}/2 - 650mV$. The DC voltage level at this pin forms an internal reference for the voltage levels at pins 5, 8, 11 and 12. Pin 10 must be bypassed to ground with a 0.1μF capacitor for proper operation of the circuit.

Loop Phase Detector Output (Pin 11): This terminal provides a high impedance output for the loop phase detector. The PLL loop filter is formed by R_1 and C_1 connected to pin 11 (see *Figure 3.*) With no input signal, or with no phase error within the PLL, the DC level at pin 11 is very nearly equal to V_{REF}. The peak to peak voltage swing available at the phase detector output is equal to $2 \times V_{REF}$.

VCO Control Input (Pin 12): VCO free-running frequency is determined by external timing resistor, R_0, connected from this terminal to ground. The VCO free-running frequency, f_O, is:

$$f_O = \frac{1}{R_0 \cdot C_0} \; Hz$$

where C_0 is the timing capacitor across pins 13 and 14. For optimum temperature stability, R_0 must be in the range of 10KΩ to 100KΩ (see *Figure 9.*)

This terminal is a low impedance point, and is internally biased at a DC level equal to V_{REF}. The maximum timing current drawn from pin 12 must be limited to ≤ 3mA for proper operation of the circuit.

VCO Timing Capacitor (Pins 13 and 14): VCO frequency is inversely proportional to the external timing capacitor, C_0, connected across these terminals (see *Figure 6.*) C_0 must be non-polar, and in the range of 200pF to 10μF.

VCO Frequency Adjustment: VCO can be fine-tuned by connecting a potentiometer, R_X, in series with R_0 at pin 12 (see *Figure 10.*)

VCO Free-Running Frequency, f_O: XR-2211 does not have a separate VCO output terminal. Instead, the VCO outputs are internally connected to the phase detector sections of the circuit. For set-up or adjustment purposes, the VCO free-running frequency can be tuned by using the generalized circuit in *Figure 3*, and applying an alternating bit pattern of O's and 1's at the known mark and space frequencies. By adjusting R_0, the VCO can then be tuned to obtain a 50% duty cycle on the FSK output (pin 7). This will ensure that the VCO f_O value is accurately referenced to the mark and space frequencies.

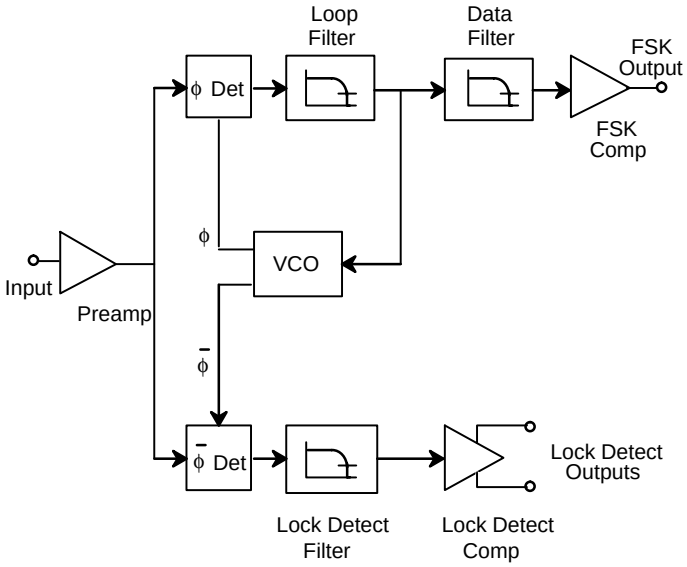


Figure 2. Functional Block Diagram of a Tone and FSK Decoding System Using XR-2211

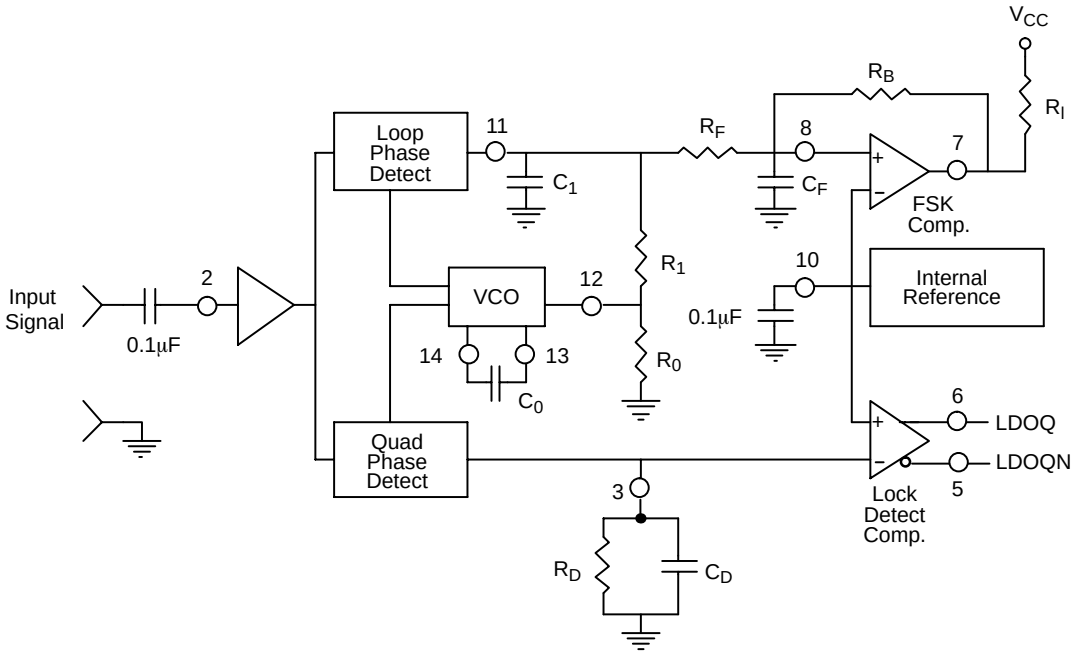


Figure 3. Generalized Circuit Connection for FSK and Tone Detection

DESIGN EQUATIONS

(All resistance in Ω, all frequency in Hz and all capacitance in farads, unless otherwise specified)

(See *Figure 3* for definition of components)

1. VCO Center Frequency, f_O:

$$f_O = \frac{1}{R_0 \cdot C_0}$$

2. Internal Reference Voltage, V_{REF} (measured at pin 10):

$$V_{REF} = \left(\frac{V_{CC}}{2}\right) - 650mV \text{ in volts}$$

3. Loop Low-Pass Filter Time Constant, τ:

$$\tau = C_1 \cdot R_{PP} \text{ (seconds)}$$

where:

$$R_{PP} = \left(\frac{R_1 \cdot R_F}{R_1 + R_F}\right)$$

if R_F is ∞ or C_F reactance is ∞, then R_{PP} = R1

4. Loop Damping, ς:

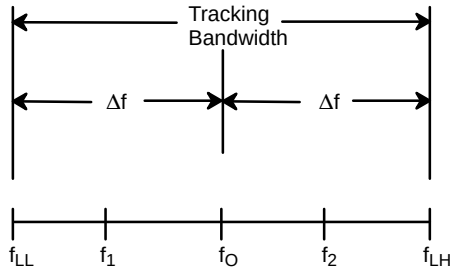
$$\zeta = \sqrt{\left(\frac{1250 \cdot C_0}{R_1 \cdot C_1}\right)}$$

Note: *For derivation/explanation of this equation, please see TAN-011.*

5. Loop-tracking

bandwidth, $\pm = \frac{\Delta f}{f_0}$

$$\frac{\Delta f}{f_0} = \frac{R_0}{R_1}$$



6. FSK Data filter time constant, tF:

$$\tau_F = \frac{R_B \cdot R_F}{(R_B + R_F)} \cdot C_F \ (seconds)$$

7. Loop phase detector conversion gain, Kd: (Kd is the differential DC voltage across pin 10 and pin11, per unit of phase error at phase detector input):

$$K_d = \frac{V_{REF} \cdot R_1}{10,000 \cdot \pi} \left[\frac{volt}{radian}\right]$$

Note: *For derivation/explanation of this equation, please see TAN-011.*

8. VCO conversion gain, Ko: (Ko is the amount of change in VCO frequency, per unit of DC voltage change at pin 11):

$$K_0 = \frac{-2\pi}{V_{REF} \cdot C_0 \cdot R_1} = \left(\frac{radian/second}{volt}\right)$$

9. The filter transfer function:

$$F(s) = \frac{1}{1 + SR_1 \cdot C_1} \ at\ 0\ Hz. \qquad S = J\omega \ and \ \omega = 0$$

10. Total loop gain. K_T:

$$K_T = K_O \cdot K_d \cdot F(s) = \left(\frac{R_F}{5,000 \cdot C_0 \cdot (R_1 + R_F)}\right)\left[\frac{1}{seconds}\right]$$

11. Peak detector current I_A:

$$I_A = \frac{V_{REF}}{20,000} \ (V_{REF} \ in \ volts \ and \ I_A \ in \ amps)$$

Note: *For derivation/explanation of this equation, please see TAN-011.*

APPLICATIONS INFORMATION

FSK Decoding

Figure 10 shows the basic circuit connection for FSK decoding. With reference to *Figure 3* and *Figure 10*, the functions of external components are defined as follows: R_0 and C_0 set the PLL center frequency, R_1 sets the system bandwidth, and C_1 sets the loop filter time constant and the loop damping factor. C_F and R_F form a one-pole post-detection filter for the FSK data output. The resistor R_B from pin 7 to pin 8 introduces positive feedback across the FSK comparator to facilitate rapid transition between output logic states.

Design Instructions:

The circuit of *Figure 10* can be tailored for any FSK decoding application by the choice of five key circuit components: R_0, R_1, C_0, C_1 and C_F. For a given set of FSK mark and space frequencies, f_O and f_1, these parameters can be calculated as follows:

(All resistance in Ω's, all frequency in Hz and all capacitance in farads, unless otherwise specified)

a) Calculate PLL center frequency, f_O:

$$f_O = \sqrt{F_1 \cdot F_2}$$

b) Choose value of timing resistor R_0, to be in the range of 10KΩ to 100KΩ. This choice is arbitrary. The recommended value is R_0 = 20KΩ. The final value of R_0 is normally fine-tuned with the series potentiometer, R_X.

$$R_O = R_O + \frac{R_X}{2}$$

c) Calculate value of C0 from design equation (1) or from *Figure 7*:

$$C_O = \frac{1}{R_0 \cdot f_0}$$

d) Calculate R1 to give the desired tracking bandwidth (See design equation 5).

$$R_1 = \frac{R_0 \cdot f_0}{(f_1 - f_2)} \cdot 2$$

e) Calculate C1 to set loop damping. (See design equation 4):

Normally, ς = 0.5 is recommended.

$$C_1 = \frac{1250 \cdot C_0}{R_1 \cdot \varsigma^2}$$

f) The input to the XR-2211 may sometimes be too sensitive to noise conditions on the input line. *Figure 4* illustrates a method of de-sensitizing the XR-2211 from such noisy line conditions by the use of a resistor, Rx, connected from pin 2 to ground. The value of Rx is chosen by the equation and the desired minimum signal threshold level.

$$V_{IN}\ minimum\ (peak) = V_a - V_b = \Delta V \pm 2.8mV\ offset = V_{REF}\frac{20,000}{(20,000 + R_X)}\ or\ R_X = 20,000\left(\frac{V_{REF}}{\Delta V} - 1\right)$$

V_{IN} minimum (peak) input voltage must exceed this value to be detected (equivalent to adjusting V threshold)

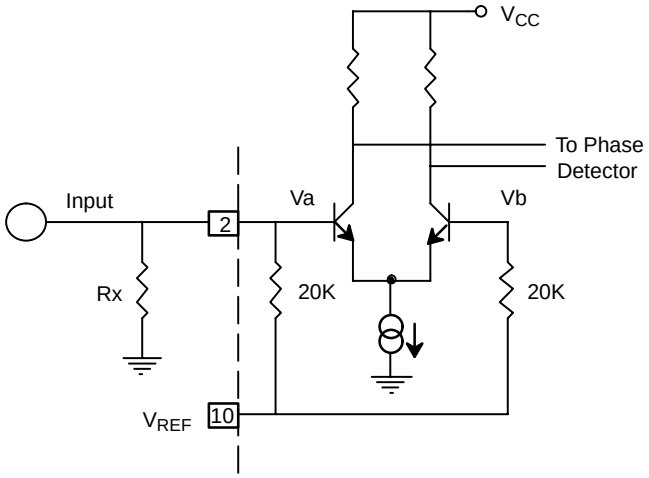


Figure 4. Desensitizing Input Stage

g) Calculate Data Filter Capacitance, C_F:

$$R_{sum} = \frac{(R_F + R_1)\cdot R_B}{(R_1 + R_F + R_B)}$$

$$C_F = \frac{0.25}{(R_{sum}\cdot Baud\ Rate)} \qquad Baud\ rate\ in\ \frac{1}{seconds}$$

Note: *All values except R_0 can be rounded to nearest standard value.*

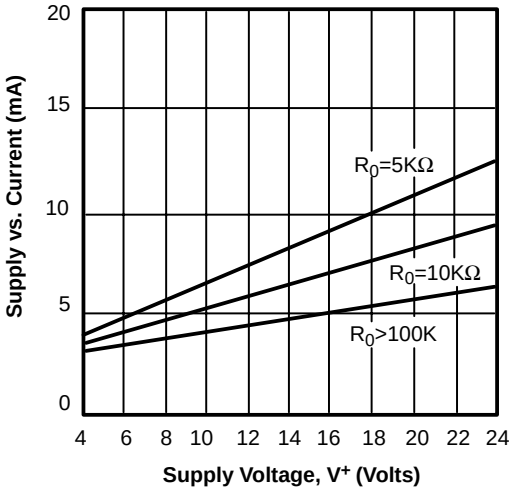


Figure 5. Typical Supply Current vs. V+ (Logic Outputs Open Circuited)

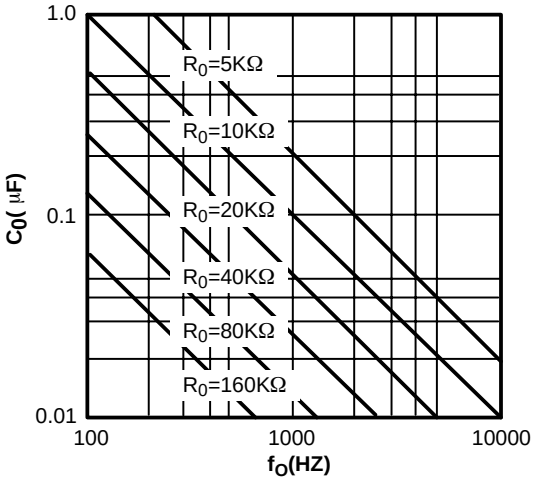


Figure 6. VCO Frequency vs. Timing Resistor

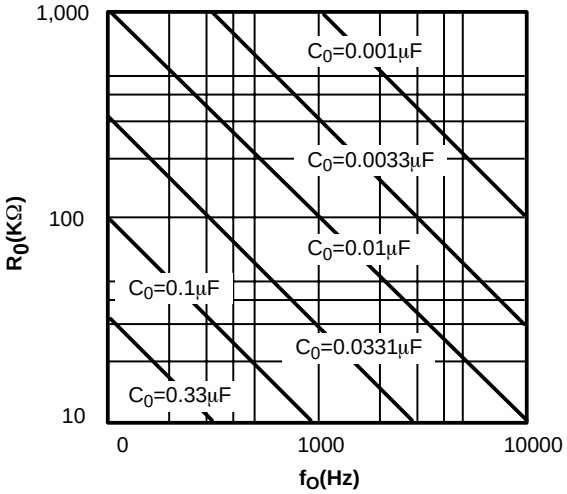


Figure 7. VCO Frequency vs. Timing Capacitor

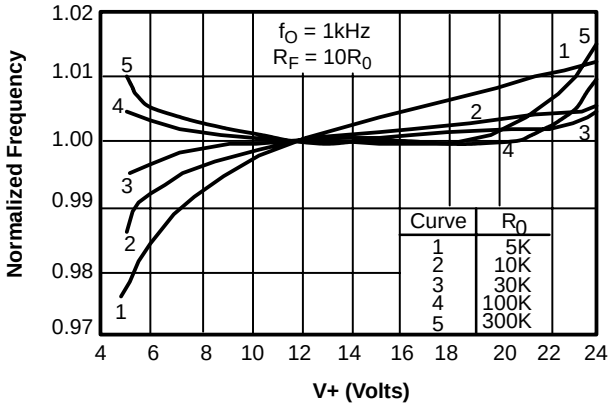


Figure 8. Typical f_O vs. Power Supply Characteristics

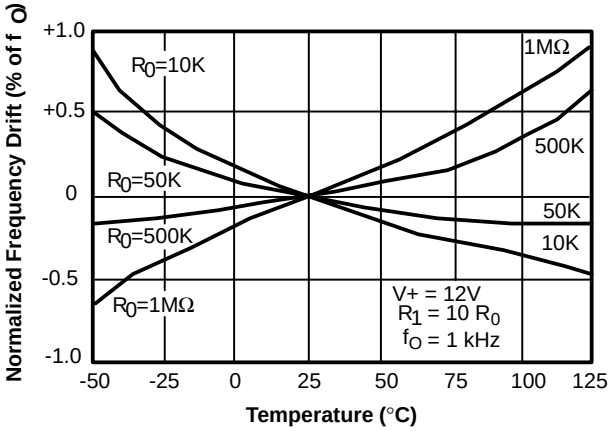


Figure 9. Typical Center Frequency Drift vs. Temperature

Design Example:

1200 Baud FSK demodulator with mark and space frequencies of 1200/2200.

Step 1: Calculate f_O: from design instructions

(*a*) $f_O = \sqrt{1200 \cdot 2200} = 1624$

Step 2: Calculate R_0 : R_0 =10K with a potentiometer of 10K. (See design instructions (b))

(*b*) $R_T = 10 + \left(\frac{10}{2}\right) = 15K$

Step 3: Calculate C_0 from design instructions

(*c*) $C_O = \frac{1}{15000 \cdot 1624} = 39nF$

Step 4: Calculate R_1 : from design instructions

(*d*) $R_1 = \frac{20000 \cdot 1624 \cdot 2}{(2200 - 1200)} = 51,000$

Step 5: Calculate C_1 : from design instructions

(*e*) $C_1 = \frac{1250 \cdot 39nF}{51000 \cdot 0.5^2} = 3.9nF$

Step 6: Calculate R_F : R_F should be at least five times R_1, R_F = 51,000·5 = 255 KΩ

Step 7: Calculate R_B : R_B should be at least five times R_F, R_B = 255,000·5 = 1.2 MΩ

Step 8: Calculate R_{SUM} :

$$R_{SUM} = \frac{(R_F + R_1) \cdot R_B}{(R_F + R_1 + R_B)} = 240K\Omega$$

Step 9: Calculate C_F :

$$C_F = \frac{0.25}{(R_{SUM} \cdot Baud\ Rate)} = 1nF$$

Note: *All values except R_0 can be rounded to nearest standard value.*

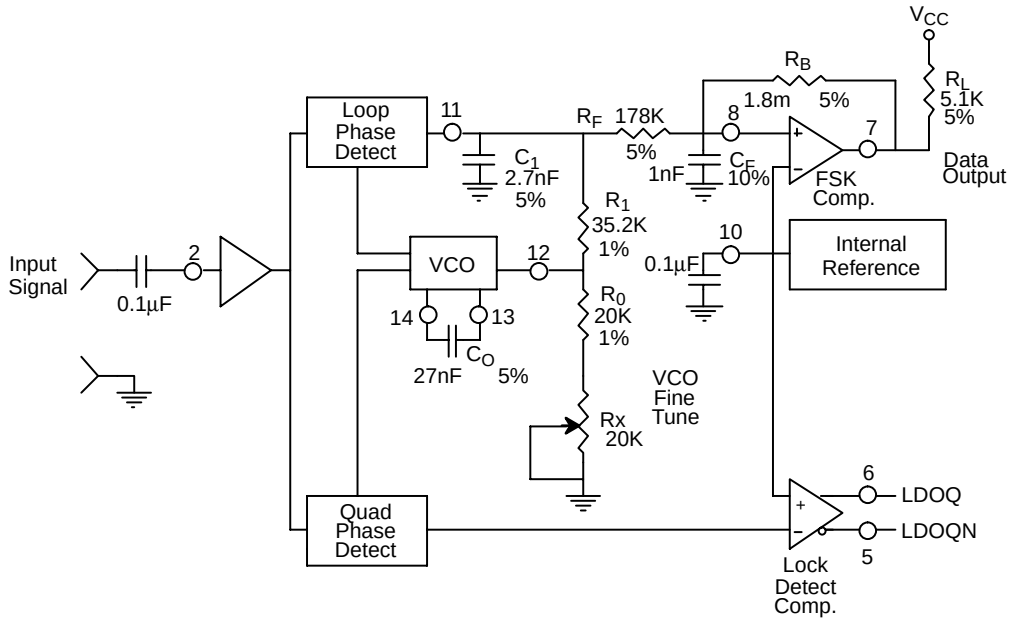


Figure 10. Circuit Connection for FSK Decoding of Caller Identification Signals (Bell 202 Format)

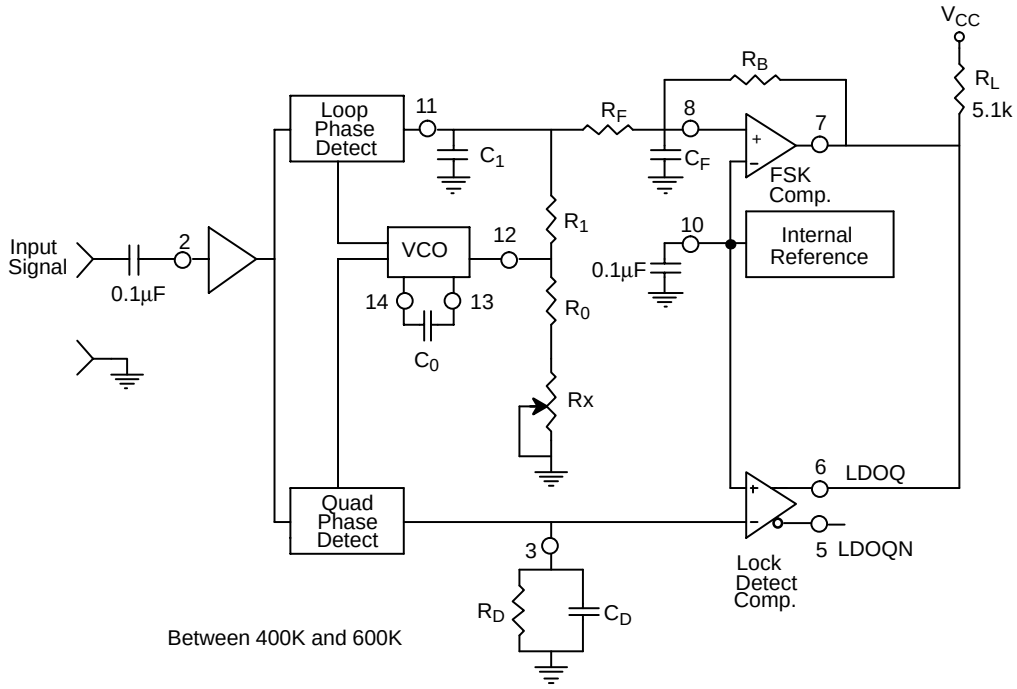


Figure 11. External Connectors for FSK Demodulation with Carrier Detect Capability

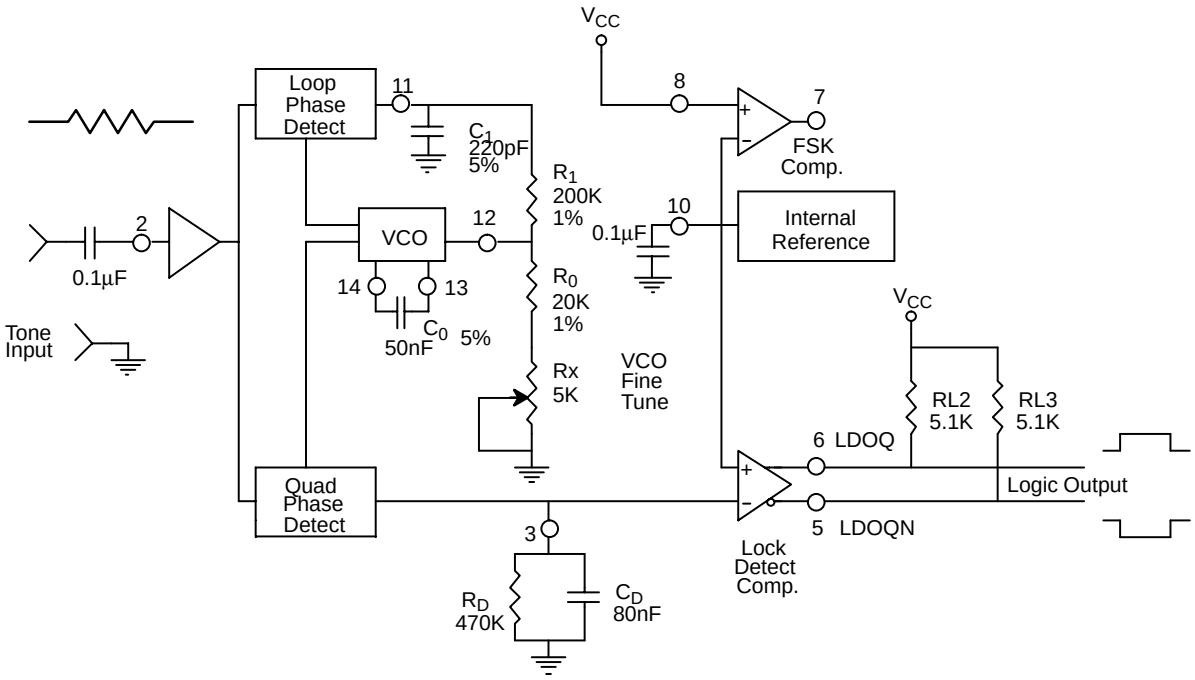


Figure 12. Circuit Connection for Tone Detection

FSK Decoding with Carrier Detect

The lock detect section of XR-2211 can be used as a carrier detect option for FSK decoding. The recommended circuit connection for this application is shown in *Figure 11.* The open collector lock detect output, pin 6, is shorted to data output (pin 7). Thus, data output will be disabled at "low" state, until there is a carrier within the detection band of the PLL and the pin 6 output goes "high" to enable the data output.

Note: *Data Output is "Low" When No Carrier is Present.*

The minimum value of the lock detect filter capacitance C_D is inversely proportional to the capture range, $\pm\Delta fc$. This is the range of incoming frequencies over which the loop can acquire lock and is always less than the tracking range. It is further limited by C_1. For most applications, $\Delta fc > \Delta f/2$. For $R_D = 470K\Omega$, the approximate minimum value of C_D can be determined by:

$$C_D > \frac{16}{\Delta f} \quad C \text{ in } \mu F \text{ and } f \text{ in Hz.}$$

C in µF and f in Hz.

With values of C_D that are too small, chatter can be observed on the lock detect output as an incoming signal frequency approaches the capture bandwidth. Excessively large values of C_D will slow the response time of the lock detect output. For Caller I.D. applications choose $C_D = 0.1\mu F$.

Tone Detection

Figure 12 shows the generalized circuit connection for tone detection. The logic outputs, LDOQN and LDOQ at pins 5 and 6 are normally at "high" and "low" logic states, respectively. When a tone is present within the detection band of the PLL, the logic state at these outputs become reversed for the duration of the input tone. Each logic output can sink 5mA of load current.

Both outputs at pins 5 and 6 are open collector type stages, and require external pull-up resistors R_{L2} and R_{L3}, as shown in *Figure 12.*

With reference to *Figure 3* and *Figure 12*, the functions of the external circuit components can be explained as follows: R_0 and C_0 set VCO center frequency; R_1 sets the detection bandwidth; C_1 sets the low pass-loop filter time constant and the loop damping factor.

Design Instructions:

The circuit of *Figure 12* can be optimized for any tone detection application by the choice of the 5 key circuit components: R_0, R_1, C_0, C_1 and C_D. For a given input, the tone frequency, f_S, these parameters are calculated as follows:

(All resistance in Ω's, all frequency in Hz and all capacitance in farads, unless otherwise specified)

a) Choose value of timing resistor R_0 to be in the range of 10KΩ to 50KΩ. This choice is dictated by the max./min. current that the internal voltage reference can deliver. The recommended value is R_0 = 20KΩ. The final value of R_0 is normally fine-tuned with the series potentiometer, R_X.

b) Calculate value of C_0 from design equation (1) or from *Figure 7* $f_S = f_O$:

$$C_O = \frac{1}{R_0 \cdot fs}$$

c) Calculate R_1 to set the bandwidth $\pm\Delta f$ (See design equation 5):

$$R_1 = \frac{R_0 \cdot f_0 \cdot 2}{\Delta f}$$

Note: *The total detection bandwidth covers the frequency range of* $f_O \pm \Delta f$

d) Calculate value of C_1 for a given loop damping factor:

Normally, $\varsigma = 0.5$ is recommended.

$$C_1 = \frac{1250 \cdot C_0}{R_1 \cdot \varsigma^2}$$

Increasing C_1 improves the out-of-band signal rejection, but increases the PLL capture time.

e) Calculate value of the filter capacitor C_D . To avoid chatter at the logic output, with R_D = 470KΩ, C_D must be:

$$C_D > \frac{16}{\Delta f} \quad C \text{ in } \mu F$$

Increasing C_D slows down the logic output response time.

Design Examples:

Tone detector with a detection band of ± 100Hz:

a) Choose value of timing resistor R_0 to be in the range of 10KΩ to 50KΩ. This choice is dictated by the max./min. current that the internal voltage reference can deliver. The recommended value is R_0 = 20 KΩ. The final value of R_0 is normally fine-tuned with the series potentiometer, R_X.

b) Calculate value of C_0 from design equation (1) or from *Figure 6* $f_S = f_O$:

$$C_0 = \frac{1}{R_0 \cdot f_S} = \frac{1}{20,000 \cdot 1,000} = 50nF$$

c) Calculate R_1 to set the bandwidth $\pm\Delta f$ (See design equation 5):

$$R_1 = \frac{R_0 \cdot f_O \cdot 2}{\Delta f} = \frac{20,000 \cdot 1,000 \cdot 2}{100} = 400K$$

Note: *The total detection bandwidth covers the frequency range of $f_O \pm \Delta f$*

d) Calculate value of C_0 for a given loop damping factor:

Normally, $\varsigma = 0.5$ is recommended.

$$C_1 = \frac{1250 \cdot C_0}{R_1 \cdot \varsigma^2} = \frac{1250 \cdot 50 \cdot 10^{-9}}{400,000 \cdot 0.5^2} = 6.25pF$$

Increasing C_1 improves the out-of-band signal rejection, but increases the PLL capture time.

e) Calculate value of the filter capacitor C_D . To avoid chatter at the logic output, with R_D = 470KΩ, C_D must be:

$$C_D = \frac{16}{\Delta f} \geq \frac{16}{200} \geq 80nF$$

Increasing C_D slows down the logic output response time.

f) Fine tune center frequency with 5KΩ potentiometer, R_X.

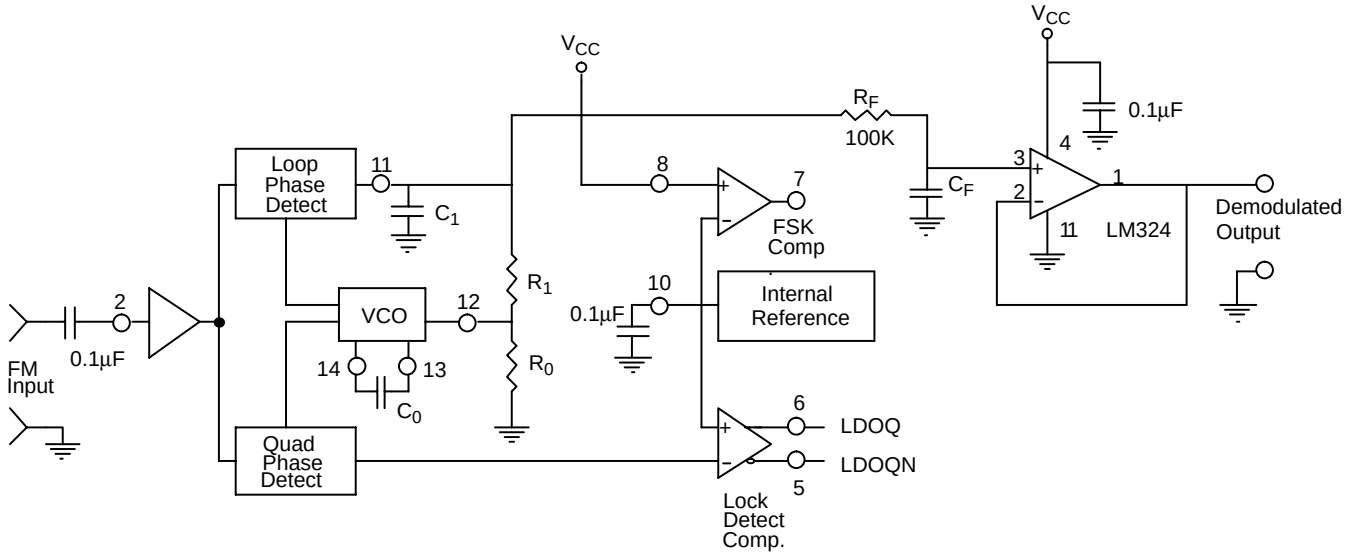


Figure 13. Linear FM Detector Using XR-2211 and an External Op Amp.
(See Section on Design Equation for Component Values.)

Linear FM Detection

XR-2211 can be used as a linear FM detector for a wide range of analog communications and telemetry applications. The recommended circuit connection for this application is shown in *Figure 13.* The demodulated output is taken from the loop phase detector output (pin 11), through a post-detection filter made up of R_F and C_F, and an external buffer amplifier. This buffer amplifier is necessary because of the high impedance output at pin 11. Normally, a non-inverting unity gain op amp can be used as a buffer amplifier, as shown in *Figure 13.*

The FM detector gain, i.e., the output voltage change per unit of FM deviation can be given as:

$$V_{OUT} = \frac{R_1 \cdot V_{REF}}{100 \cdot R_0}$$

where VR is the internal reference voltage ($V_{REF} = V_{CC}/2$ - 650mV). For the choice of external components R_1, R_0, C_D, C_1 and C_F, see the section on design equations.

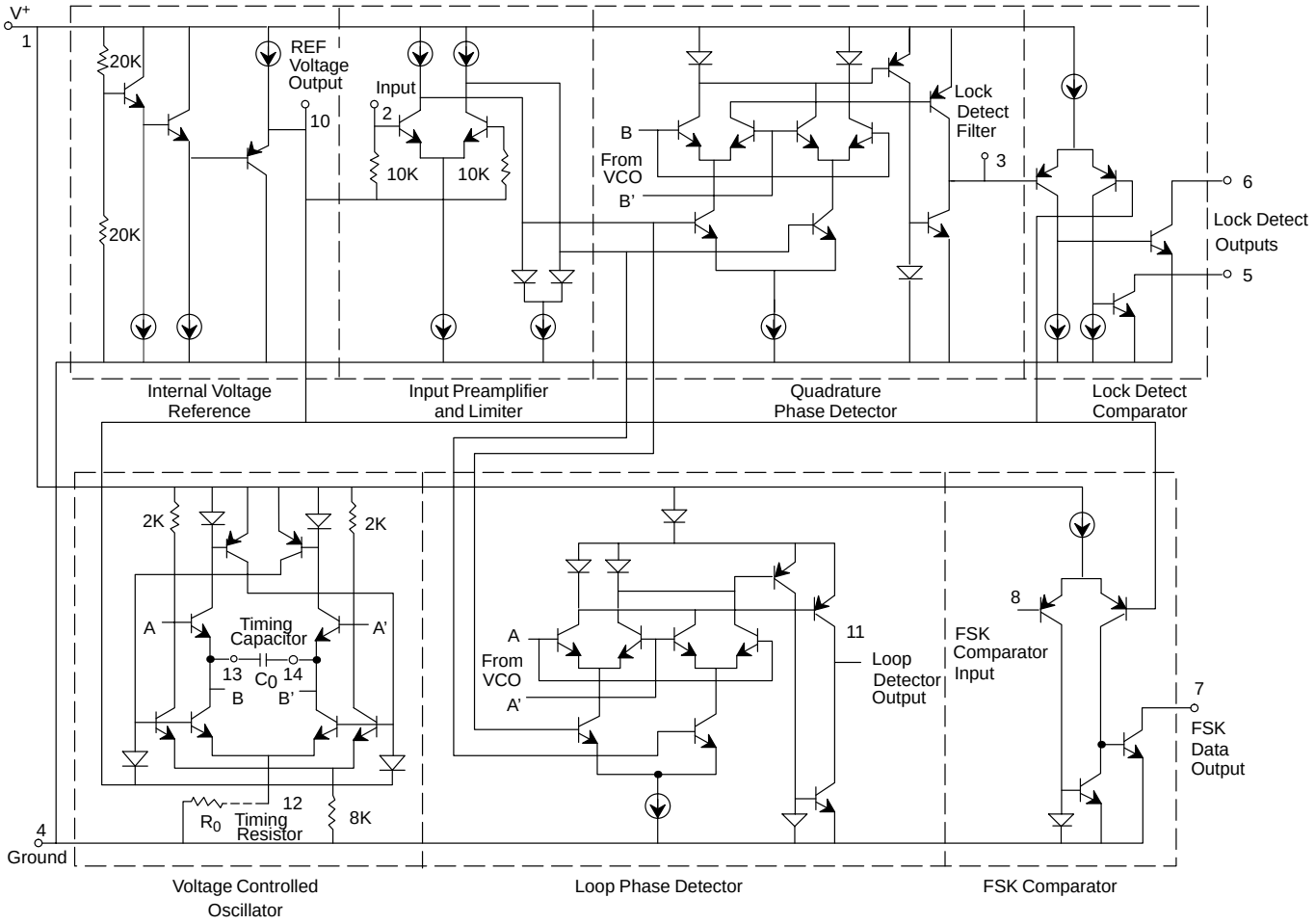
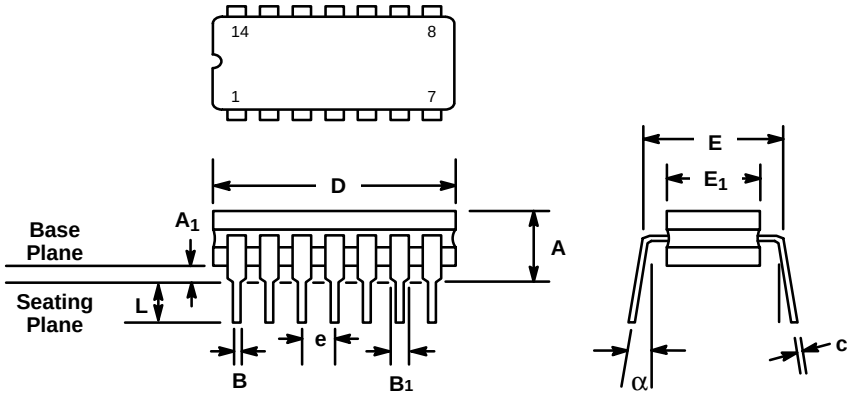


Figure 14. Equivalent Schematic Diagram

14 LEAD CERAMIC DUAL-IN-LINE (300 MIL CDIP)

Rev. 1.00

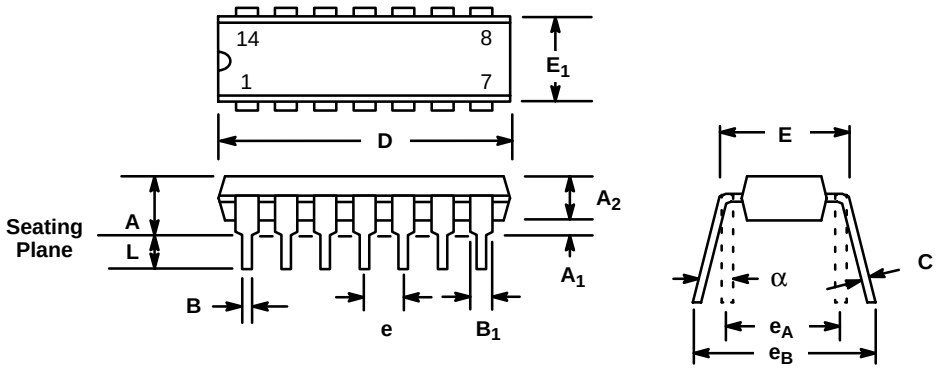


SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.100	0.200	2.54	5.08
A_1	0.015	0.060	0.38	1.52
B	0.014	0.026	0.36	0.66
B_1	0.045	0.065	1.14	1.65
c	0.008	0.018	0.20	0.46
D	0.685	0.785	17.40	19.94
E_1	0.250	0.310	6.35	7.87
E	0.300 BSC		7.62 BSC	
e	0.100 BSC		2.54 BSC	
L	0.125	0.200	3.18	5.08
α	0°	15°	0°	15°

Note: The control dimension is the inch column

14 LEAD PLASTIC DUAL-IN-LINE (300 MIL PDIP)

Rev. 1.00

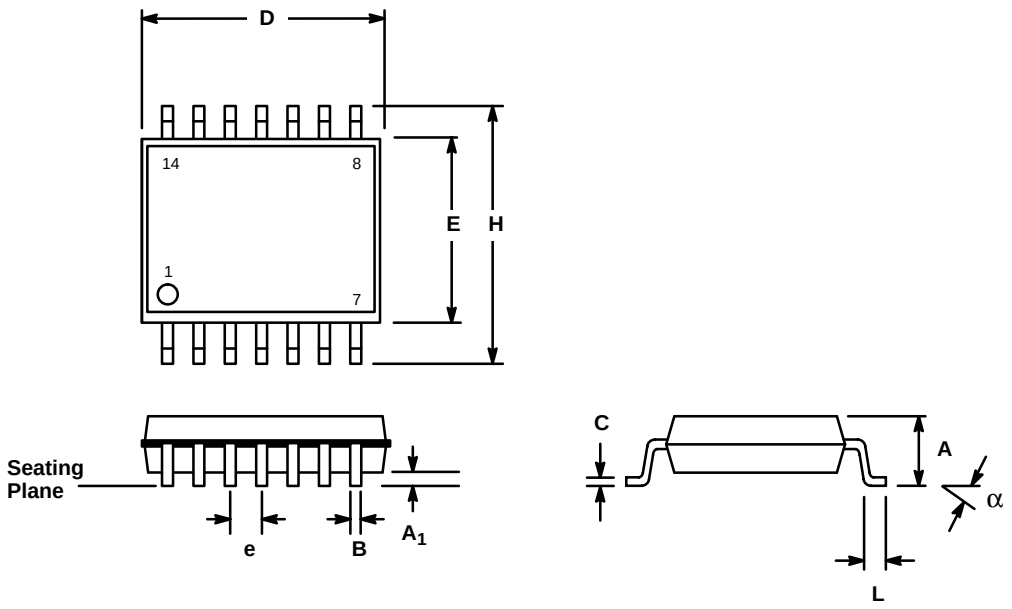


SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.145	0.210	3.68	5.33
A_1	0.015	0.070	0.38	1.78
A_2	0.115	0.195	2.92	4.95
B	0.014	0.024	0.36	0.56
B_1	0.030	0.070	0.76	1.78
C	0.008	0.014	0.20	0.38
D	0.725	0.795	18.42	20.19
E	0.300	0.325	7.62	8.26
E_1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
e_A	0.300 BSC		7.62 BSC	
e_B	0.310	0.430	7.87	10.92
L	0.115	0.160	2.92	4.06
α	0°	15°	0°	15°

Note: The control dimension is the inch column

14 LEAD SMALL OUTLINE
(150 MIL JEDEC SOIC)

Rev. 1.00



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.053	0.069	1.35	1.75
A_1	0.004	0.010	0.10	0.25
B	0.013	0.020	0.33	0.51
C	0.007	0.010	0.19	0.25
D	0.337	0.344	8.55	8.75
E	0.150	0.157	3.80	4.00
e	0.050 BSC		1.27 BSC	
H	0.228	0.244	5.80	6.20
L	0.016	0.050	0.40	1.27
α	0°	8°	0°	8°

Note: The control dimension is the millimeter column

Notes

Notes

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